Integrated AC LED Solution

Acrich3 - 08W

SMJE-XD08W4PX











## **Product Brief**

## **Description**

- The Acrich3 series of products are not need the standard converter essential for conventional general lighting products.
- The converter or driver found in most general lighting products can limit the overall life of the product, but with the Acrich3 series of products the life of the product can more closely be estimated from the LED itself. This will also allow for a much smaller form factor from an overall fixture design allowing for higher creativity in the fixture.
- The modules have a high power factor which can contribute to a higher energy savings in the end application.

### **Features and Benefits**

- Connects directly to AC line voltage
- High Power Efficiency & Factor
- Low THD
- Long Life Time
- Simple BOM
- Miniaturization
- · Lead Free Product
- RoHS Compliant
- TRIAC Dimming

### **Key Applications**

Bulb Llight

**Table 1. Product Selection (CCT)** 

Part No.	Vin [Vac]	P [W]	Color	сст [к]	CRI Min.
			Cool	4700 – 6000	
SMJE-2D08W4PD SMJE-3D08W4PD	120 220	8.5	Neutral	3700 – 4200	80
OIVIOL SDOOVVAI D	220		Warm	2600 - 3200	
01415 000014105			Cool	4700 – 6000	
SMJE-2D08W4PE SMJE-3D08W4PE	120 220	8.5	Neutral	3700 – 4200	90
SIVIOE SDOOW 41 E	220		Warm	2600 - 3200	

**Table 2. Product Selection (Flux)** 

Part No.	Vin [Vac]	P [W]	CRI	Flux	[lm]	Remark
rait No.	VIII [Vac]	L [AA]	CKI	Min.	Тур.	Kemark
SMJE-2D08W4PD	120	8.5	80	670	750	08b
SMJE-3D08W4PD	220	0.5		750	830	08c
SMJE-2D08W4PE SMJE-3D08W4PE	120 220	8.5	90	580	670	08a

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## **Performance Characteristics**

Table 3. Electro Optical Characteristics, T<sub>a</sub> = 25°C

Barrandar	0		Value		1124	Manta
Parameter	Symbol	Min.	Тур.	Max.	Unit	Mark
Luminous Flux	Φ <sub>V</sub> <sup>[2]</sup>	670	790	-	- lm	@CRI80
Luminous Flux	Ψ <sub>V</sub> ι-ι	580	670	-	· IIII	@CRI90
		5300	5600	6000		В
		4700	5000	5300		С
Correlated Color Temperature [3]	CCT	3700	4000	4200	K	E
		2900	3000	3200		G
		2600	2700	2900		Н
CDI	D-	80	-	-	-	PD
CRI	Ra	90	-	-	-	PE
lanut Valtana [4]			120		\/	2D
Input Voltage [4]	$V_{in}$		220		- Vac	3D
Power Consumption	Р	7.6	8.5	9.4	W	W80
Operating Frequency	f		50 / 60		Hz	
Davis Faster	D.F.		Over 0.95		-	@120V
Power Factor	PF		0ver 0.75		-	@220V
Viewing Angle	20 <sub>1/2</sub>		120		deg.	
Tolerance of Surge [5]	V <sub>s</sub>	500	-	-	V	
Transient Protection [6]	V <sub>s</sub>	2500	-	-	V	

## Notes:

- (1) At 120Vac/220Vac,  $T_a = 25^{\circ}C$
- (2)  $\Phi_{\rm V}$  is the total luminous flux output measured with an integrated sphere. (Measure tolerance :  $\pm 5\%)$
- (3) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (4) Operating Voltage doesn't indicate the maximum voltage which customers use but means tolerable voltage according to each country's voltage variation rate. It is recommended that the solder pad temperature should be below 70 °C.
- (5) Surge withstand in accordance with IEC61000-4-5
- (6) At 120Vac, seven strikes, 100kHz 2.5kV in accordance with ANSI/IEEE C62.41.2-2002 Category A operation

# **Performance Characteristics**

Table 4. Absolute Maximum Ratings,  $T_a = 25^{\circ}C$ 

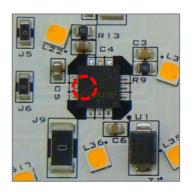
Parameter	Symbol	Unit	Value
Maximum Input Voltage @120Vac	V	\/a-a	144
Maximum Input Voltage @220Vac	$V_{in}$	Vac	264
Power Consumption	Р	W	9.7
Operating Temperature	T <sub>s</sub>	°C	<70℃
Storage Temperature	T <sub>stg</sub>	°C	-40 ~ 100
ESD Sensitivity	-	-	±4,000V HBM

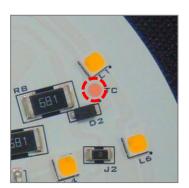
# **Thermal Resistance**

Table 5. Thermal information, Ta = 25°C

Part	Maximum Junction Temperature [℃]	Rθ <sub>js</sub> [℃/W]
Acrich3 LED	125	9
Acrich3 IC	150	11.25

#### Notes:





The Acrich3 module is recommended to keep the junction temperature under maximum junction temperature spec. (Table 5)

LED lead temperature and IC top case temperature are measured with thermocupler. (Fig1)

LED & IC juntion temperatures can be calculated using the formulas below.

$$T_{s \text{ max}} = T_{i \text{ max}} - (R\theta_{i-s} * P_d)$$

< Example >

If LED lead temperature and IC top temerature are 110  $^{\circ}$ C

1) LED juntion temperature

$$T_J = T_S + (R\theta_{j-s} * P_d)$$
  
= 110°C + (9°C/W \* 0.84W) = 117.56°C

2) IC junction temperature

$$T_J = T_S + (R\theta_{j-s} * P_d)^{(1)}$$
  
= 110°C + (11.25°C/W \* 2.8W) = 141.5°C

 $^{\star}$  (1) : In the example,  $\mathrm{P_{d}}$  value is the power consumption of IC when the rated voltage.

Fig 1. Relative Spectral Distribution vs. Wavelength Characteristic - G, H

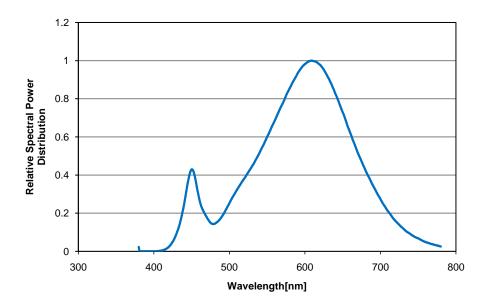


Fig 2. Relative Spectral Distribution vs. Wavelength Characteristic - E

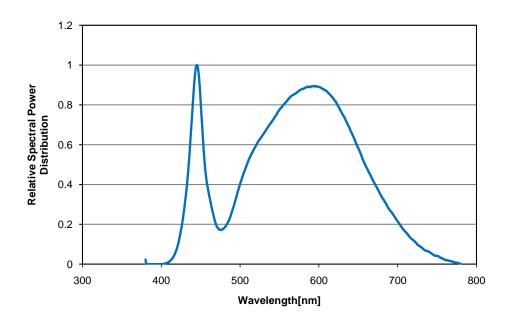


Fig 3. Relative Spectral Distribution vs. Wavelength Characteristic - B, C

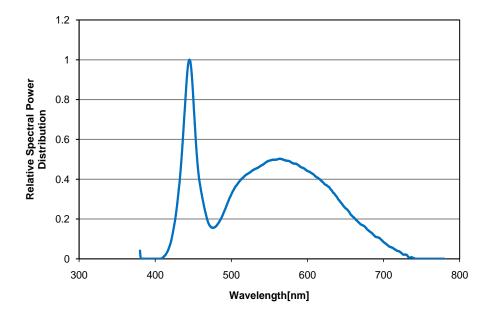


Fig 4. Relative Power Distribution vs. Voltage,  $T_a = 25 \, ^{\circ} C$ , 120V

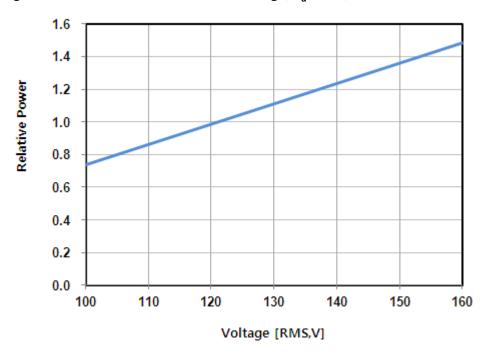


Fig 5. Relative Power Distribution vs. Voltage,  $T_a = 25 \, ^{\circ} \! \text{C}$ , 220V

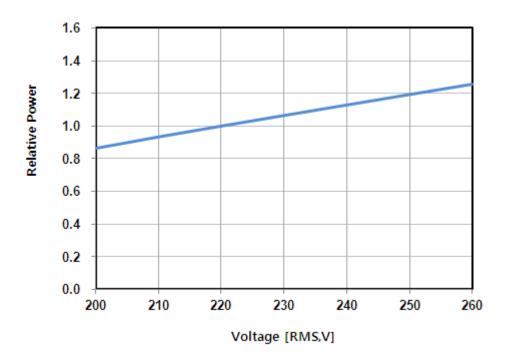


Fig 6. Relative Luminous Flux vs. Voltage,  $T_a = 25 \, ^{\circ}\text{C}$ , 120V

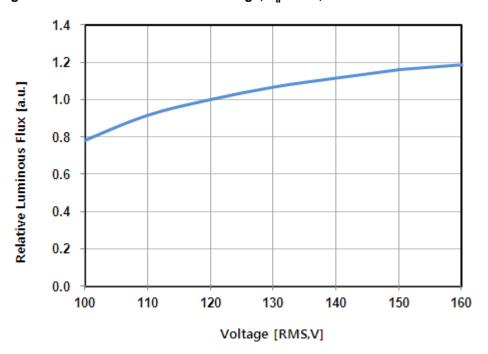


Fig 7. Relative Luminous Flux vs. Voltage,  $T_a = 25 \, ^{\circ}\text{C}$ , 220V

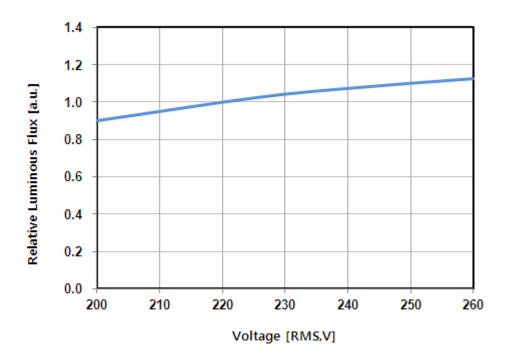
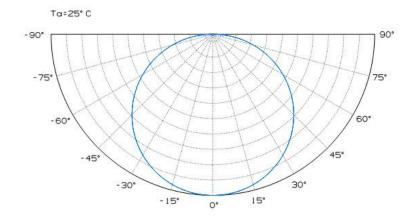
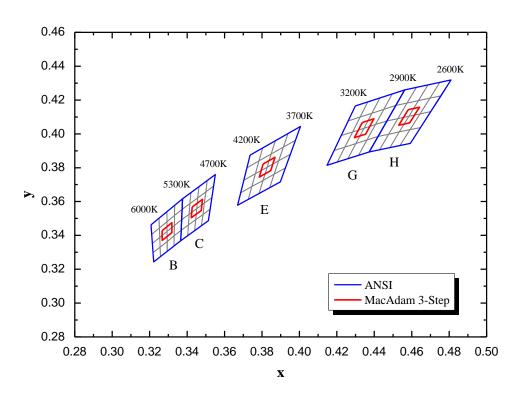
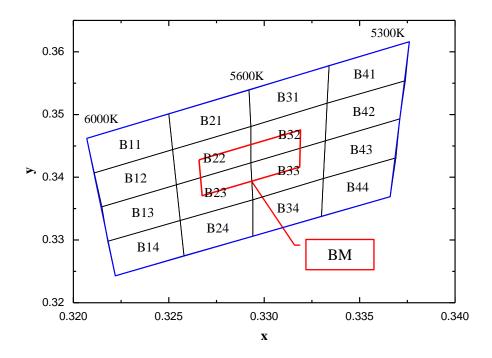


Fig 8. Radiant Pattern,  $T_a = 25 \,^{\circ}$ C

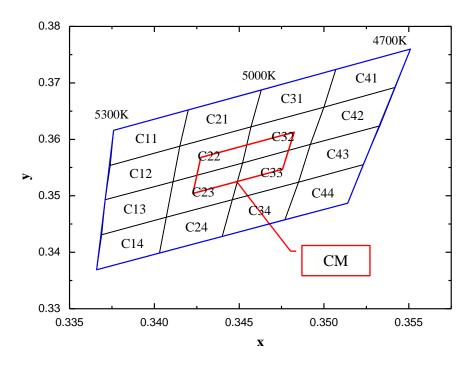




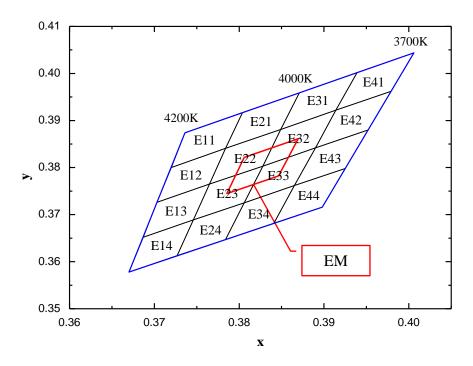
Bin	x	у	Bin	x	у	Bin	x	у
	0.3266	0.3428		0.3427	0.3568		0.3806	0.3822
ВМ	0.3268	0.3371	· CM	0.3423	0.3504	- EM -	0.3786	0.3745
DIVI	0.3319	0.3416	CIVI	0.3476	0.3547		0.3846	0.3782
	0.3319	0.3476		0.3482	0.3613		0.3870	0.3861
	0.4336	0.4067		0.4581	0.4143			
GM	0.4294	0.3977	. нм	0.4531	0.4051			
GIVI	0.4354	0.3999	. TIW	0.4589	0.4065			
	0.4398	0.4089	-	0.4641	0.4157			



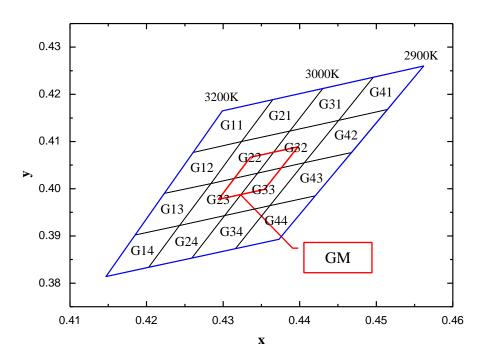
Bin	x	у	Bin	x	у	Bin	х	у	Bin	х	у
	0.3207	0.3462		0.3250	0.3501		0.3292	0.3539		0.3334	0.3578
B11	0.3211	0.3407	B21	0.3252	0.3444	B31	0.3293	0.3481	B41	0.3333	0.3518
611	0.3252	0.3444	B21	0.3293	0.3481	БЭТ	0.3333	0.3518	D41	0.3374	0.3554
	0.3250	0.3501		0.3292	0.3539		0.3334	0.3578		0.3376	0.3616
	0.3211	0.3407		0.3252	0.3444		0.3293	0.3481		0.3333	0.3518
B12	0.3215	0.3353		0.3254	0.3388	B32	0.3293	0.3423	B42	0.3332	0.3458
B12	0.3254	0.3388		0.3293	0.3423	В32	0.3332	0.3458	. 642	0.3371	0.3493
	0.3252	0.3444		0.3293	0.3481		0.3333	0.3518		0.3374	0.3554
	0.3215	0.3353		0.3254	0.3388		0.3293	0.3423		0.3332	0.3458
B13	0.3218	0.3298	B23	0.3256	0.3331	B33	0.3294	0.3364	B/12	0.3331	0.3398
B13	0.3256	0.3331	623	0.3294	0.3364	Б33	0.3331	0.3398	B43	0.3369	0.3431
	0.3254	0.3388		0.3293	0.3423		0.3332	0.3458		0.3371	0.3493
	0.3218	0.3298		0.3256	0.3331		0.3294	0.3364		0.3331	0.3398
B14	0.3222	0.3243	B24	0.3258	0.3275	B34	0.3294	0.3306	· B44	0.3330	0.3338
	0.3258	0.3275	B24 -	0.3294	0.3306	D34	0.3330	0.3338	D74	0.3366	0.3369
	0.3256	0.3331		0.3294	0.3364		0.3331	0.3398		0.3369	0.3431



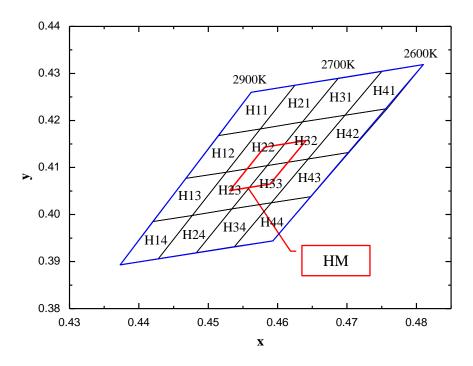
Bin	x	у	Bin	x	у	Bin	х	у	Bin	х	у
	0.3376	0.3616		0.3420	0.3652		0.3463	0.3687		0.3507	0.3724
C11	0.3374	0.3554	C21	0.3415	0.3588	C31	0.3457	0.3622	C41	0.3500	0.3657
	0.3415	0.3588	GZ1	0.3457	0.3622	CSI	0.3500	0.3657	C41	0.3542	0.3692
	0.3420	0.3652		0.3463	0.3687	-	0.3507	0.3724		0.3551	0.3760
	0.3374	0.3554		0.3415	0.3588		0.3457	0.3622		0.3500	0.3657
C12	0.3371	0.3493	Caa	0.3411	0.3525	C32	0.3452	0.3558	C42	0.3492	0.3591
CIZ	0.3411	0.3525	C22	0.3452	0.3558	C32	0.3492	0.3591		0.3533	0.3624
	0.3415	0.3588		0.3457	0.3622		0.3500	0.3657		0.3542	0.3692
	0.3371	0.3493		0.3411	0.3525		0.3452	0.3558		0.3492	0.3591
C13	0.3369	0.3431	C23	0.3407	0.3462	C33	0.3446	0.3493	C43	0.3485	0.3524
013	0.3407	0.3462	023	0.3446	0.3493	033	0.3485	0.3524	C43	0.3523	0.3555
	0.3411	0.3525		0.3452	0.3558		0.3492	0.3591		0.3533	0.3624
	0.3369	0.3431		0.3407	0.3462		0.3446	0.3493		0.3485	0.3524
C14	0.3366	0.3369	C24	0.3403	0.3399	C34	0.3440	0.3428	· C44	0.3477	0.3458
	0.3403	0.3399	C24 -	0.3440	0.3428	034	0.3477	0.3458	044	0.3514	0.3487
	0.3407	0.3462		0.3446	0.3493		0.3485	0.3524		0.3523	0.3555



Bin	x	у	Bin	x	у	Bin	x	у	Bin	x	у
	0.3736	0.3874		0.3804	0.3917		0.3871	0.3959		0.3939	0.4002
E11	0.3720	0.3800	E21	0.3784	0.3841	E31	0.3849	0.3881	E41	0.3914	0.3922
= ''	0.3784	0.3841	<b>EZ</b> 1	0.3849	0.3881	ESI	0.3914	0.3922		0.3979	0.3962
	0.3804	0.3917		0.3871	0.3959		0.3939	0.4002		0.4006	0.4044
	0.3720	0.3800		0.3784	0.3841		0.3849	0.3881		0.3914	0.3922
E12	0.3703	0.3726	E22	0.3765	0.3765	E32	0.3828	0.3803	E42	0.3890	0.3842
[12	0.3765	0.3765	<b>C22</b>	0.3828	0.3803	E32 ·	0.3890	0.3842	C42	0.3952	0.3880
	0.3784	0.3841		0.3849	0.3881		0.3914	0.3922		0.3979	0.3962
	0.3703	0.3726		0.3765	0.3765		0.3828	0.3803		0.3890	0.3842
E13	0.3687	0.3652	E23	0.3746	0.3689	E33	0.3806	0.3725	E42	0.3865	0.3762
	0.3746	0.3689	LZJ	0.3806	0.3725	E33	0.3865	0.3762	E43	0.3925	0.3798
	0.3765	0.3765		0.3828	0.3803		0.3890	0.3842		0.3952	0.3880
	0.3687	0.3652		0.3746	0.3689		0.3806	0.3725		0.3865	0.3762
E14	0.3670	0.3578	E24	0.3727	0.3613	E3/	0.3784	0.3647	E44	0.3841	0.3682
-1-	0.3727	0.3613	E24 -	0.3784	0.3647	– E34	0.3841	0.3682	L77	0.3898	0.3716
	0.3746	0.3689		0.3806	0.3725		0.3865	0.3762		0.3925	0.3798



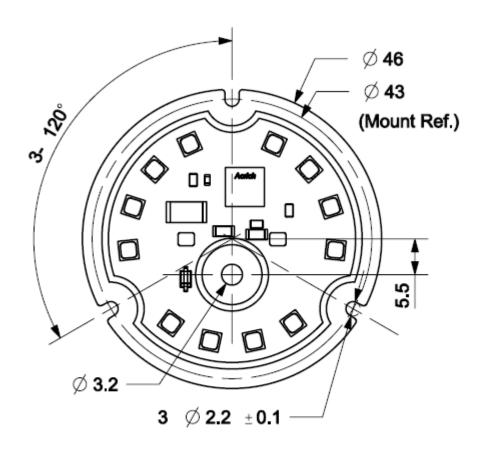
Bin	x	у	Bin	х	у	Bin	х	у	Bin	х	у
	0.4299	0.4165		0.4364	0.4188		0.4430	0.4212		0.4496	0.4236
G11	0.4261	0.4077	G21	0.4324	0.4099	G31	0.4387	0.4122	G41	0.4451	0.4145
911	0.4324	0.4100	<b>G21</b>	0.4387	0.4122	GSI	0.4451	0.4145	-	0.4514	0.4168
	0.4365	0.4189		0.4430	0.4212		0.4496	0.4236		0.4562	0.4260
	0.4261	0.4077		0.4324	0.4100		0.4387	0.4122		0.4451	0.4145
G12	0.4223	0.3990	G22	0.4284	0.4011	G32	0.4345	0.4033	G42	0.4406	0.4055
Giz	0.4284	0.4011	GZZ	0.4345	0.4033	G32	0.4406	0.4055		0.4468	0.4077
	0.4324	0.4100		0.4387	0.4122		0.4451	0.4145		0.4515	0.4168
	0.4223	0.3990		0.4284	0.4011		0.4345	0.4033		0.4406	0.4055
G13	0.4185	0.3902	G23	0.4243	0.3922	G33	0.4302	0.3943	G43	0.4361	0.3964
013	0.4243	0.3922	G23	0.4302	0.3943	<b>G</b> 33	0.4361	0.3964	G43	0.4420	0.3985
	0.4284	0.4011		0.4345	0.4033		0.4406	0.4055		0.4468	0.4077
	0.4243	0.3922		0.4302	0.3943		0.4302	0.3943		0.4361	0.3964
G14	0.4203	0.3834	G24	0.4259	0.3853	G34	0.4259	0.3853	- - G44	0.4316	0.3873
314	0.4147	0.3814	<b>G24</b>	0.4203	0.3834	- G34	0.4316	0.3873	044	0.4373	0.3893
	0.4185	0.3902		0.4243	0.3922		0.4361	0.3964		0.4420	0.3985



Bin	x	у	Bin	x	у	Bin	x	у	Bin	х	у
	0.4562	0.4260	H21	0.4625	0.4275		0.4687	0.4289		0.4750	0.4304
H11	0.4515	0.4168		0.4575	0.4182	H31	0.4636	0.4197	H41	0.4697	0.4211
"''	0.4575	0.4182		0.4636	0.4197	пот	0.4697	0.4211	П41	0.4758	0.4225
	0.4625	0.4275		0.4687	0.4289		0.4750	0.4304		0.4810	0.4319
	0.4515	0.4168		0.4575	0.4182		0.4636	0.4197		0.4697	0.4211
H12	0.4468	0.4077		0.4526	0.4090	H32	0.4585	0.4104	H42	0.4644	0.4118
1112	0.4526	0.4090		0.4585	0.4104	H32	0.4644	0.4118	. п42	0.4703	0.4132
	0.4575	0.4182		0.4636	0.4197		0.4697	0.4211		0.4758	0.4225
	0.4468	0.4077		0.4526	0.4090		0.4585	0.4104		0.4644	0.4118
H13	0.4420	0.3985	H23	0.4477	0.3998	H33	0.4534	0.4012	<b>U</b> 12	0.4591	0.4025
113	0.4477	0.3998	п23	0.4534	0.4012	поэ	0.4591	0.4025	H43	0.4648	0.4038
	0.4526	0.4090		0.4585	0.4104		0.4644	0.4118		0.4703	0.4132
	0.4420	0.3985		0.4477	0.3998		0.4534	0.4012		0.4591	0.4025
H14	0.4373	0.3893	UЭЛ	0.4428	0.3906	<b>⊔</b> 24	0.4483	0.3919	H44	0.4538	0.3932
114	0.4428	0.3906	H24 -	0.4483	0.3919	- H34	0.4538	0.3932	П44	0.4593	0.3944
	0.4477	0.3998		0.4534	0.4012		0.4591	0.4025		0.4648	0.4038

# **Mechanical Dimensions**

## SMJE-2D08W4PX (120V)





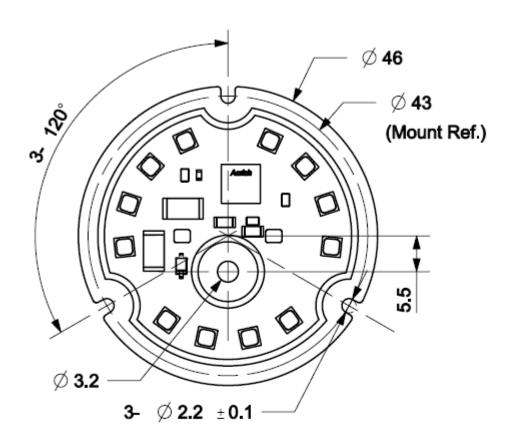
#### Notes:

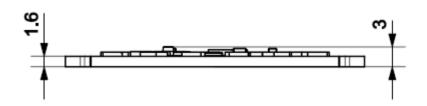
(1) All dimensions are in millimeters. (Tolerance :  $\pm 0.2$ )

(2) Scale: None

# **Mechanical Dimensions**

**SMJE-3D08W4PX (220V)** 



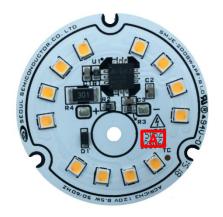


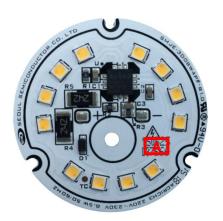
#### Notes

(1) All dimensions are in millimeters. (Tolerance :  $\pm 0.2)$ 

(2) Scale: None

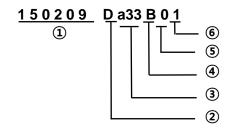
# **Marking Information**





A: 150209 Da33B01

- Description



- ① SMT Date (YYMMDD, 6 Digits)
- ② CRI (1 Digits, CRI80=D, CRI90=E)
- 3 Module Flux Bin (3 Digits)
- 4 CCT (1 Digit)
- **⑤** CCT Combination NO. (1 Digit)
- **(6)** VF Combination NO. (1 Digit)

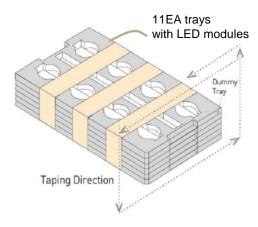
2		3				4, 5			6		
Marking	CRI	Туре	Marking	Bin A	Bin B	Marking	Bin A	Bin B	Marking	Bin A	Bin B
D	80		88			*0	*22	*33	1	D1	D1
Е	90	а	99	580	670	*1	*23	*32	2	D1	D2
			11			*2	*33	*22	3	D2	D1
		b	33	670	750	*3	*32	*23	4	D1	D3
	,		55	070	730	*4	*MC	*MC	5	D3	D1
		С	77	750	830	*5	*22	*22	6	D2	D2
						*6	*23	*23	7	D2	D3
						*7	*32	*32	8	D3	D2
						*8	*33	*33	9	D3	D3
						*9	*22	*34			
						*A	*22	*43			
						*B	*22	*44	_		
						*C	*23	*31			
						*D	*23	*41			
						*E	*23	*42	_		
						*F	*32	*13			
						*G	*32	*14			
						*H	*32	*24	_		
						*	*33	*11			
						*J	*33	*12			
						*K	*33	*21			

# **Packing**

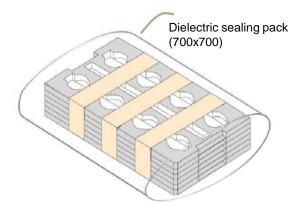
## 1. Tray information



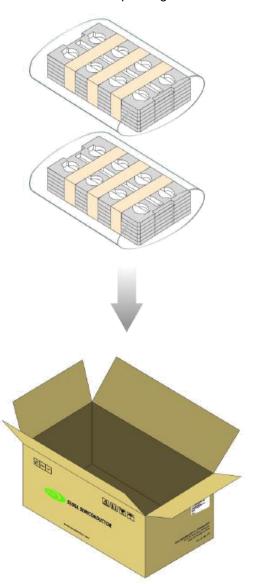
- 72 PCS LED modules packed per tray
- 2. Tray stack and taping



- 11 LED module trays and additional 1 dummy trays each up of box
- Add silica gel (1EA) on top of the tray
- 3. Sealing packing



## 4. Box information & packing



- 720 PCS modules per BOX 1EA
- \*\* 1 Box : 720 PCS per tray x 20 trays = 720 PCS

# **Label Information**

Model No.	SMJD-XD08W4PX (1)				
Rank	08bG803 <sup>(2)</sup>				
Туре	3-step <sup>(3)</sup>				
Quantity	XX				
Date	YYMDDXXXXX-XXXXXXX				
SEOUL	SEOUL SEMICONDUCTOR CO.,LTD.				

#### **Notes**

(1) The model number designation is explained as follow

SMJD : Seoul Semiconductor internal code XD : Input Voltage (2D = 120V, 3D = 220V)

08W : About Power Consumption

4: Acrich IC Version 3.0

PX: MJT PKG (D=SAW8C72A, E=SAW9C72A)

(2) It represents Module Optical SPEC.

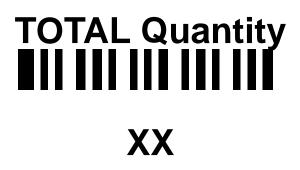
Luminous flux: 08a, 08b, 08c

CCT: H~B CRI: 80 or 90

CIE Area: 3 or 4(3step or 4step)
(3) It represents module CIE SPEC

CIE Area: 3step or 4step

(4) It is attached to the top of a sealing pack & the bottom right corner of the box.





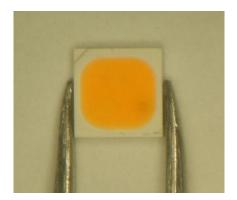
SEOUL SEMICONDUCTOR CO.,LTD.

#### **Notes**

(1) It is attached to the bottom right corner of the box.

# **Handling of Silicone Resin for LEDs**





- (1) Acrich3 series is encapsulated with silicone resin for high optical efficiency.
- (2) Please do not touch the silicone resin area with sharp objects such as pincette(tweezers).
- (3) Finger prints on silicone resin area may affect the performance.
- (4) Please store LEDs in covered containers to prevent dust accumulation as this may affect performance.
- (5) Excessive force more than 3000gf to the silicone lens can result in fatal or permanent damage with LEDs.
- (6) Please do not cover the silicone resin area with any other resins such as epoxy, urethane, etc.

## **Precaution for Use**

- (1) Please review the Acrich3 Application Note for proper protective circuitry usage.
- (2) Please note, Acrich3 products run off of high voltage, therefore caution should be taken when working near Acrich3 products.
- (3) Make sure proper discharge prior to starting work.
- (4) DO NOT touch any of the circuit board, components or terminals with body or metal while circuit is active.
- (5) Please do not add or change wires while Acrich3 circuit is active.
- (6) Long time exposure to sunlight or UV can cause the lens to discolor.
- (7) Please do not use adhesives to attach the LED that outgas organic vapor.
- (8) Please do not use together with the materials containing Sulfur.
- (9) Please do not assemble in conditions of high moisture and/or oxidizing gas such as CI, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, NO<sub>x</sub>, etc.
- (10) Please do not make any modification on module.
- (11) Please be cautious when soldering to board so as not to create a short between different trace patterns.
- (12) Do not impact or place pressure on this product because even a small amount of pressure can damage the product. The product should also not be placed in high temperatures, high humidity or direct sunlight since the device is sensitive to these conditions.
- (13) When storing devices for a long period of time before usage, please following these guidelines:
  - \* The devices should be stored in the anti-static bag that it was shipped in from Seoul-Semiconductor with opening.
  - \* If the anti-static bag has been opened, re-seal preventing air and moisture from being present in the bag.
- (14) LEDs and IC are sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). The acrich3 product should also not be installed in end equipment without ESD protection. Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.
- a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LEDs may cause the product to demonstrate unusual characteristics such as:

## **Precaution for Use**

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

#### Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

#### b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
  (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires
- This damage usually appears due to the thermal stress produced during the EOS event
- c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:
  - A surge protection circuit
  - An appropriately rated over voltage protection device
  - A current limiting device



# **Company Information**

#### Published by

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#### **Company Information**

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

#### **Legal Disclaimer**

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